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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/051,267	01/18/2002	Tsutomu Tanaka	9792909-5359	2710
26263 7	590 07/31/2002			
	HEIN NATH & ROS	EXAMINER		
	IVE STATION	TRAN, THIEN F		
CHICAGO, IL	CHICAGO, IL 60606-1080			PAPER NUMBER
				2811
			DATE MAILED: 07/31/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)			
	10/051,267	TANAKA ET AL.			
Office Action Summary	Examiner	Art Unit			
	Thien F Tran	2811			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the	correspondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM					
THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply if NO period for reply is specified above, the maximum statutory period with the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	66(a). In no event, however, may a reply be ti within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS fron cause the application to become ABANDON	mely filed ys will be considered timely. n the mailing date of this communication. ED (35 U.S.C. § 133).			
1) Responsive to communication(s) filed on	·				
2a) ☐ This action is FINAL . 2b) ☑ Thi	is action is non-final.				
3) Since this application is in condition for alloward closed in accordance with the practice under	ince except for formal matters, p Ex parte Quayle, 1935 C.D. 11,	prosecution as to the merits is 453 O.G. 213.			
Disposition of Claims	nnlication				
4) Claim(s) 1-3,10 and 12 is/are pending in the a					
4a) Of the above claim(s) <u>10 and 12</u> is/are with	urawii irom consideration.				
5) Claim(s) is/are allowed.					
6) Claim(s) 1-3 is/are rejected.					
7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or	r election requirement				
Application Papers	election requirement.				
9) The specification is objected to by the Examine	r.				
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.					
If approved, corrected drawings are required in reply to this Office action.					
12)☐ The oath or declaration is objected to by the Examiner.					
Priority under 35 U.S.C. §§ 119 and 120					
13) Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. § 119(a)-(d) or (f).			
a) ☐ All b) ☐ Some * c) ⊠ None of:					
1. Certified copies of the priority document	s have been received.				
 2. Certified copies of the priority document 	s have been received in Applica	tion No			
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
14) Acknowledgment is made of a claim for domesti	c priority under 35 U.S.C. § 119	(e) (to a provisional application).			
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.					
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informa	ry (PTO-413) Paper No(s) I Patent Application (PTO-152)			

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DETAILED ACTION

Election/Restrictions

Applicant's election of claims 1-3 in Paper No. 4 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

Priority

Acknowledgment is made of applicant's claim for foreign priority based on an application filed in Japan on 04-06-2000. It is noted, however, that applicant has not filed a certified copy of the foreign application as required by 35 U.S.C. 119(b).

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in-
- (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or
- (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).

Claims 1-3 are rejected under 35 U.S.C. 102(e) as being anticipated by Yamazaki et al. (US 6,246,070).

Yamazaki et al. discloses the claimed bottom-gate thin film transistor (Fig. 3) comprising a gate electrode 102, a gate insulating film 103, an active layer 106, an LDD

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region 114, a source-drain region 113, and a protective insulating film (105, 108) formed in that order on a substrate 100, wherein the protective insulating film has a thickness of 5 to 50 nm, and the protective insulating film is formed on the active layer.

Regarding claim 2, the active layer 106 comprises a polysilicon film.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thien F Tran whose telephone number is (703) 308-4108. The examiner can normally be reached on 8:00AM - 4:30PM Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9318 for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

tt July 26, 2002

Thien Tran
Patent Examiner
Technology Center 2800